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# FX50KMJ-06

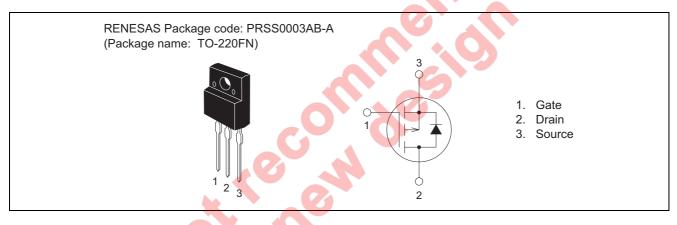
High-Speed Switching Use Pch Power MOS FET

> REJ03G1451-0200 (Previous: MEJ02G0277-0101) Rev.2.00 Aug 07, 2006

### Features

- Drive voltage : 4 V
- $V_{DSS}$  : -60 V
- $r_{DS(ON)(max)}$ : 18.9 m $\Omega$
- I<sub>D</sub>: -50 A
- Integrated Fast Recovery Diode (TYP.) : 70 ns
- Viso : 2000 V

### Outline



### **Applications**

Motor control, Lamp control, Solenoid control, DC-DC converters, etc.

### **Maximum Ratings**

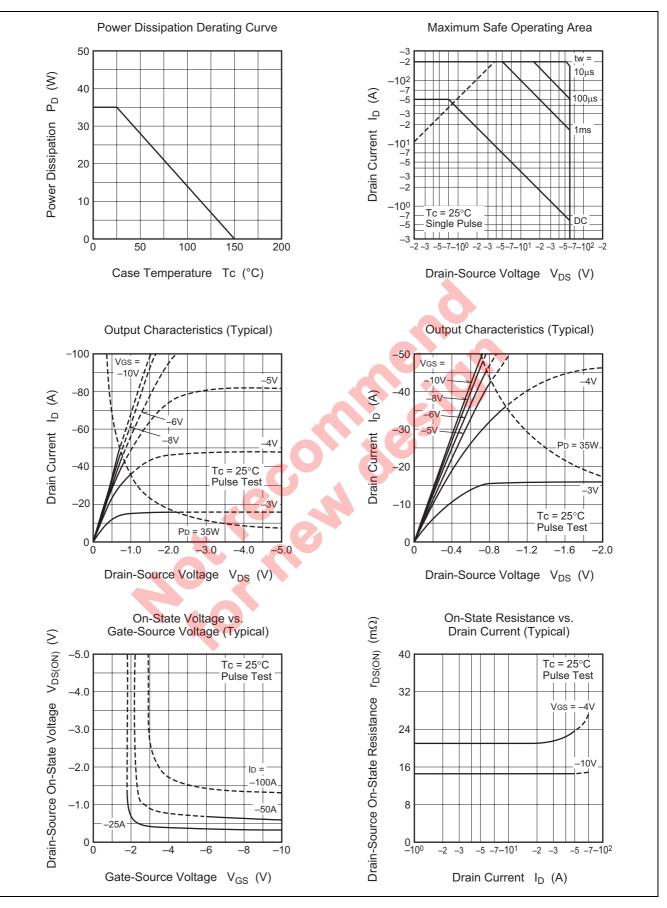
|                                  |                  |              |      | $(\mathrm{Tc} = 25^{\circ}\mathrm{C})$ |
|----------------------------------|------------------|--------------|------|--|
| Parameter                        | Symbol           | Ratings      | Unit | Conditions                             |
| Drain-source voltage             | V <sub>DSS</sub> | -60          | V    | $V_{GS} = 0 V$                         |
| Gate-source voltage              | V <sub>GSS</sub> | ±20          | V    | $V_{DS} = 0 V$                         |
| Drain current                    | ID               | -50          | A    |  |
| Drain current (Pulsed)           | I <sub>DM</sub>  | -200         | А    |  |
| Avalanche drain current (Pulsed) | I <sub>DA</sub>  | -50          | A    | L = 50 μH                              |
| Source current                   | ls               | -50          | A    |  |
| Source current (Pulsed)          | I <sub>SM</sub>  | -200         | А    |  |
| Maximum power dissipation        | PD               | 35           | W    |  |
| Channel temperature              | Tch              | - 55 to +150 | °C   |  |
| Storage temperature              | Tstg             | - 55 to +150 | °C   |  |
| Isolation voltage                | Viso             | 2000         | V    | AC for 1 minute,                       |
|                                  |                  |              |      | Terminal to case                       |
| Mass                             | _                | 2.0          | g    | Typical value                          |



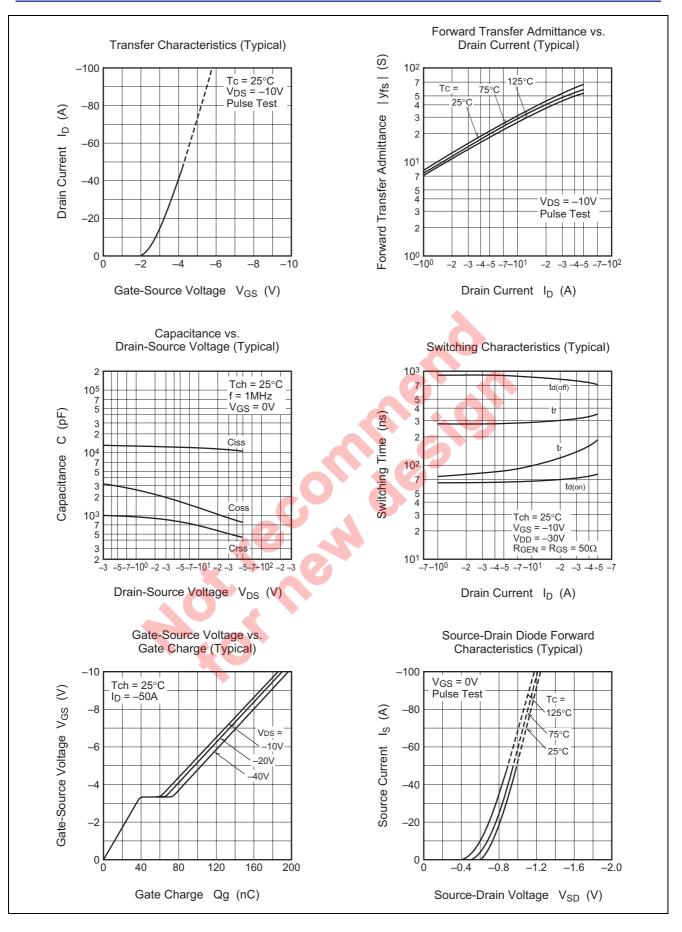
### **Electrical Characteristics**

|                                  |                       |      |       |       |      | $(Tch = 25^{\circ}C)$                                  |
|----------------------------------|-----------------------|------|-------|-------|------|--|
| Parameter                        | Symbol                | Min  | Тур   | Max   | Unit | Test Conditions  |
| Drain-source breakdown voltage   | V <sub>(BR)DSS</sub>  | -60  | —     | _     | V    | $I_D = -1 \text{ mA}, V_{GS} = 0 \text{ V}$            |
| Gate-source leakage current      | I <sub>GSS</sub>      | _    | —     | ±0.1  | μA   | $V_{GS} = \pm 20 \text{ V},  V_{DS} = 0 \text{ V}$     |
| Drain-source leakage current     | I <sub>DSS</sub>      | _    | _     | -0.1  | mA   | $V_{DS} = -60 V, V_{GS} = 0 V$                         |
| Gate-source threshold voltage    | V <sub>GS(th)</sub>   | -1.3 | -1.8  | -2.3  | V    | $I_D = -1 \text{ mA}, V_{DS} = -10 \text{ V}$          |
| Drain-source on-state resistance | r <sub>DS(ON)</sub>   | _    | 15.0  | 18.9  | mΩ   | $I_D = -25 \text{ A}, V_{GS} = -10 \text{ V}$          |
| Drain-source on-state resistance | r <sub>DS(ON)</sub>   | _    | 23    | 32    | mΩ   | $I_D = -25 \text{ A}, V_{GS} = -4 \text{ V}$           |
| Drain-source on-state voltage    | V <sub>DS(ON)</sub>   | _    | -0.38 | -0.47 | V    | $I_D = -25 \text{ A}, V_{GS} = -10 \text{ V}$          |
| Forward transfer admittance      | y <sub>fs</sub>       | —    | 49    |       | S    | $I_D = -25 \text{ A}, V_{DS} = -10 \text{ V}$          |
| Input capacitance                | Ciss                  | —    | 11610 |       | pF   | $V_{DS} = -10 V, V_{GS} = 0 V,$                        |
| Output capacitance               | Coss                  | _    | 1355  |       | pF   | f = 1MHz   |
| Reverse transfer capacitance     | Crss                  | —    | 687   | -     | pF   |  |
| Turn-on delay time               | t <sub>d(on)</sub>    | —    | 73    | _     | ns   | $V_{DD} = -30 V, I_D = -25 A,$                         |
| Rise time                        | tr                    | —    | 137   | _     | ns   | $V_{GS} = -10 V$ ,                                     |
| Turn-off delay time              | t <sub>d(off)</sub>   | —    | 822   | _     | ns   | $R_{GEN} = R_{GS} = 50 \ \Omega$                       |
| Fall time                        | t <sub>f</sub>        | —    | 320   | _     | ns   |  |
| Source-drain voltage             | V <sub>SD</sub>       |      | -1.0  | -1.5  | V    | $I_{\rm S} = -25$ A, $V_{\rm GS} = 0$ V                |
| Thermal resistance               | R <sub>th(ch-c)</sub> |      |       | 3.57  | °C/W | Channel to case  |
| Reverse recovery time            | t <sub>rr</sub>       |      | 70    |       | ns   | ls = −50 A, d <sub>is</sub> /d <sub>t</sub> = 100 A/μs |

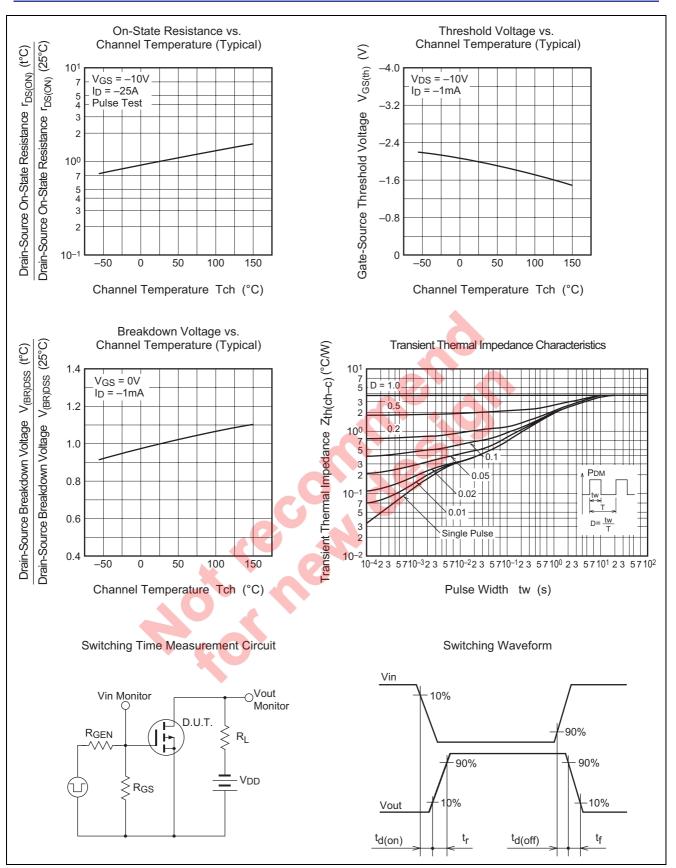
### **Performance Curves**



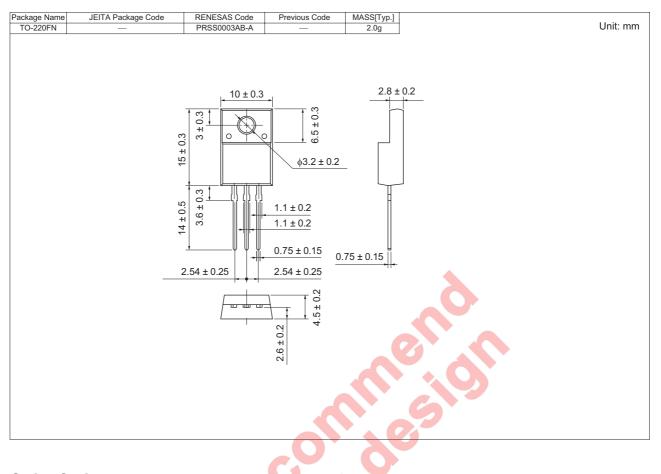








### **Package Dimensions**



### **Order Code**

| Lead form     | Standard packing        | Qua | antity | Standard order code           | Standard order<br>code example |
|---------------|-------------------------|-----|--------|-------------------------------|--------------------------------|
| Straight type | Plastic Magazine (Tube) |     | 50     | Type name                     | FX50KMJ-06                     |
| Lead form     | Plastic Magazine (Tube) |     | 50     | Type name – Lead forming code | FX50KMJ-06-A8                  |

Note: Please confirm the specification about the shipping in detail.

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